

## isc Silicon PNP Power Transistor

## 2SB1186A

### **DESCRIPTION**

- · High Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= -160V(Min.)
- Good Linearity of h<sub>FE</sub>
- Complement to Type 2SD1763A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

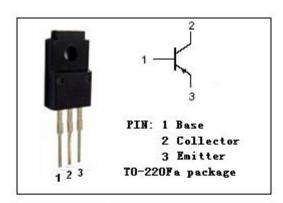
#### **APPLICATIONS**

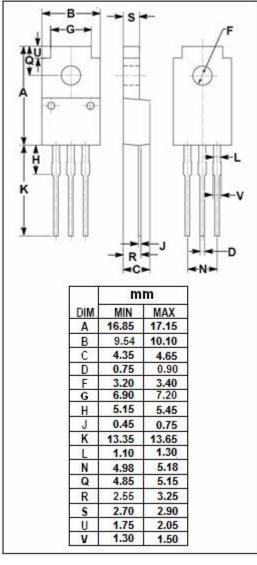
- · Power amplifier applications.
- Driver stage amplifier applications.



### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>СВО</sub>	Collector-Base Voltage	-160	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-160	V	
V <sub>ЕВО</sub>	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous -1.5		А	
Ісм	Collector Current-Peak -3		A	
D	Collector Power Dissipation @ T <sub>a</sub> =25℃	2	\A/	
Pc	Collector Power Dissipation @ T <sub>C</sub> =25°C	20	W	
TJ	Junction Temperature 150		°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -1mA; I <sub>B</sub> = 0	-160			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -50 μ A; I <sub>E</sub> = 0	-160			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -50 μ A; I <sub>C</sub> = 0	-5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -1A; I <sub>B</sub> = -0.1A			-2.0	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = -1A; I <sub>B</sub> = -0.1A			-1.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -120V; I <sub>E</sub> = 0			-1	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -4V; I <sub>C</sub> = 0			-1	μА
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -0.1A; V <sub>CE</sub> = -5V	60		200	

#### ♦ h<sub>FE</sub> Classifications

D	E
60-120	100-200

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